

The University of Manchester



VELO U2 cooling substrates

Oscar Augusto on behalf of the VELO Upgrade 2 group



VELO Module/Cooling concepts (FTDR)

- Smaller microchannel coolers to reduce the overall cost
- More challenging to integrate (interface between pipes and coolers)
- Cooling structure could be potentially re-used (<u>NA62 talk</u>)
- Better cooling performance









- Cheaper and more flexible design
- Easier to integrate (cooling plant)

VELO Module/Cooling concepts (NIKHEF)

Module concept idea

- Features:
 - One module type for all stations (but with different cabling)
 - Two tiles (front & back of substrate), with each tile consisting out of 3 ASIC's.
 - Cooling substrate (material TBD) with thickness equivalent to ~50% of current budget (0.25 mm if Silicon)
 - Two cooling connectors





3D metal

- Exploration phase
- Considering evaporative CO₂ as baseline solution
- Power dissipation of up to 2W/cm²
- Different designs submitted to the <u>Royce Institute</u> (Sheffield)
- At the moment, considering different designs which could lead to a material budget reduction compared to <u>plan-Z</u>
- More aggressive designs (larger ΔT) would require lower operating temperature (Krypton?) to keep the max. sensor temperature < $-20^{\circ}C$

U-like design

- Largest variation of temperature on the sensor part around 25°C (with respect to the inner side wall)
- Alternative strategy to cooldown off-chip electronics would have to be improved (cooling routing lines)



3D metal: LHCb VELO

- Different designs
 - U-shaped design
 - Squared tube and connector prototypes
- X-ray tomography via <u>NXCT</u>







New round of printing:

- Filling factor being improved
- Different printing parameters to improve distortions and fill factor
- Half of the samples will be electropolished (easier integration?)
- Samples are being post-processed

Ceramics

- Manufacturing at IKTS Fraunhofer (Germany)
- Different base materials: YSZ, Al_2O_3 , ... including **SiC** and **AIN**
- Manufacturing based on several layers
- <u>Why?</u>
 - Robustness, reliability, stability in ultra-high-vacuum
 - Possible to embed conductive layers in between ceramics layers and metalize the surface
 - Potential to integrate electronics or high conductivity elements
 - Mechanically robust and compatible with high ultra vacuum



Ceramics

- Experience with fluidic applications
- First prototype based on the early VELO Upgrade I CERN design
 - Initial channel with 70µm width (restrictions)
 - Channels height $100 \mu m$
 - Overall dimensions: $40 \times 60 \text{ mm}^2$
 - Based on LTCC
 - $Al_2O_3/Glass \sim 1:1$
 - HTCC at a later stage ($Al_2O_3 \sim 96\%$)
 - Possible to move to SiC or AlN



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Ceramics: Goal and status

- Goal:
 - ✓ Manufacture first samples (IKTS)
 - ✓ Miniaturized version (2x smaller inplane)
 - ✓ Expected 35um and 100um width restrictions and main channels respectively!
 - Second round being prepared
 - Validate initial prototypes to high pressure, leak tightness and cooling performance
 - Benchmark: LHCb VELO Upgrade 2 requirements (High pressure 186 bar, leak tight (vacuum operation) and excellent thermal performance
- Very encouraging first manufacturing round!!!



Metrology

- Measurements done using the smartscope
- Planarity deviation of order of tenths of μm
 - An additional layer can be deposited and machined for better planarity as we scale it up (<u>Massimo thesis</u>)
 - Discussion with the manufacturer this week
- The microchannels pattern can be seen in the surface survey
 - Cross section analysis on-going



Simplified FEA



Sensor + ASIC (400um Silicon) -> Power dissipation: 2W/cm²

Cooling structure in Al2O3 (20W/m.K)

Overhang of 5 mm as in the VELO U1

ΔT~9°C

FEA (Alumina LTCC)



Sensor + ASIC (200um Silicon) -> Power dissipation: 2W/cm²

Cooling structure in LTCC Al2O3 (5W/m.K)

Overhang of 5 mm as in the VELO U1



FEA (Alumina LTCC)



Sensor + ASIC (200um Silicon) -> Power dissipation: 2W/cm²

Cooling structure in LTCC Al2O3 (5W/m.K)

Overhang of 8 mm as in the VELO U1

ΔT~28.6°C



VELO U1 TDR

VELO Upgrade I TDR

- 1. Cooling substrate at **baby prototypes** level
 - SNAKEI, 40 mm x 60 mm
 - Main channel 200 um x 70 um (Restriction 30 um x 70 um)
- 2. Robustness tests running
 - 1. High pressure and cycling



Figure 61: (left) The 2012, $6 \times 4 \text{ cm}^2$ silicon-glass prototype. (right) The end of the highimpedance, restricted-width region where the evaporation is triggered in the larger volume.





VELO Upgrade I TDR

VELO U1 TDR

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 - SNAKEI, 40 mm x 60 mm
 - Main channel 200 um x 70 um (Restriction 30 um x 70 um)
- 2. Robustness tests running
 - 1. High pressure and cycling
- 3. Fluidic and **cooling performance** test $(\Delta T \sim 6.5^{\circ}C)$



Figure 64: Experimental setup used to test cooling performance. Heater mockups are used to simulate the heat dissipation of the ASICs and irradiated silicon sensors. Cooling is provided by a microchannel substrate.



Figure 65: Measured temperature differential with fully powered ASICS and a gradual increase in power dissipation in the sensor. The end-of-lifetime expectation corresponds to a power dissipation of ~ 13 W. The three colours correspond to three temperature probes; probe uch3 is located furthest from the microchannels and is hence the hardest point to cool.

VELO U1 TDR

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- 2. Robustness tests running
 - 1. High pressure and cycling
- 3. Fluidic and **cooling performance** test $(\Delta T \sim 6.5^{\circ}C)$
- 4. Finite element analysis (FEA) to optimize the channels distribution and cooling performance



Figure 66: Thermal map from the microchannel FEA simulations, with a cross section illustrating the optimal channel separation and the very small temperature gradients to the heat source.



Figure 67: Thermal map from the microchannel FEA simulations, with a a view of the full module with nominal heating. The maximum ΔT to the silicon tip, from which the cooling substrate is retracted, is estimated to be about 7°C.

VELO Upgrade I TDR

VELO Upgrade I TDR

VELO U1 TDR

- 1. Cooling substrate at *baby* prototypes level
 - SNAKEI, 40 mm x 60 mm
 - Main channel 200 um x 70 um (Restriction 30 um x 70 um)
- 2. Robustness tests running
 - 1. High pressure and cycling
- 3. Fluidic and **cooling performance** test $(\Delta T \sim 6.5^{\circ}C)$
- 4. Finite element analysis (**FEA**) to optimize the channels distribution and cooling performance
- 5. Scale the cooling substrate to **module size**
- 6. Connector attachment at the very early stages



Figure 69: Schematic of the microchannel connector, showing details of the microchannel network at the point of attachment. The metallic connector partially enters the LHCb acceptance so must be kept as small as possible, and further optimisation is envisaged.

VELO U1 TDR

| | Ceramics | 3D metal |
|-------------------------|--|--|
| <i>Baby</i> prototypes | Thinner channels were already manufactured Nominal samples by End/July | Samples produced show distortion and fill factor issues Second round should have better fill factor (TBC) |
| Robustness tests | Miniaturized connector glueing at the moment (based on the CERN design) – High pressure test in-house New connector for nominal size Cyclic tests | Connector is required (see last row) |
| Cooling performance | Heaters ordered and vacuum tank/CO2 in place (To be recommissioned) | In principle, same heaters/set-up can be used |
| Cooling FEA | On-going (large contribution due to the overhang) | On-going (large contribution due to the overhang) |
| Module scaling and Mod0 | Aiming for timepix4 prototype by mid/2025 (40 mm x 60 mm – nominal size) | Pursuit another manufacturer in parallel (Terms and conditions?) |
| Connector | IKTS has experience with integration, soldering, Hyperbar bonding (<u>CPPM</u>), brazing(?) | More samples are required (smoother finishing would be beneficial) |

Summary

- Scaling up towards the final design (highly dependent on the geometry – not defined yet!)
- Cooling plates
 - Ceramic plates
 - ✓ Miniaturized samples in-house (20 x 30 mm²)
 - Nominal dimension expected by end of July $(40 \times 60 \text{ mm}^2) \text{compatible with the first prototypes specs (timepix4 single board)}$
 - Robustness validation (high pressure / cyclic tests?)
 - Connector being assembled
 - Finite element analysis of the sample (including design optimization)
 - Connector: different approaches can be considered
 - IKTS integration, soldering, hyperbar bonding (<u>CPPM</u>), brazing, ...

Summary

Cooling plates

- 3D metal printing
 - First run shows fill factor issue and distortions
 - Second run should have better fill factor
 - Additional samples produced to understand better the printing (straight samples)
 - Another manufacturer to be identified (Alloyed, BA systems, ?)
 - Connector R&D requires more samples
 - Smoother surface is desirable

Ceramics 3D printing

- Experience with fluidic applications
- First prototype based on the SNAKEI design
 - Restrictions of $70 \mu m$ instead of $30 \mu m$
 - Channels height $100 \mu m$
 - Overall dimensions: $40x60mm^2$
 - Based on alumina (Al₂O₃)
 - Possible to move to SiC afterwards
- Currently, initial quote being discussed



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SNAKEI based design to optimize printing parameters/test feasibility



Simplified FEA focusing on the 5 mm overhang. Substrate in alumina and heat conduction on one side of the cooling plate and Stycast (100um). For $2W/cm^2$, $\Delta T \sim 9$ C.

Cooling material budget (U1)

Not all services are present (no cables)

Material budget for perpendicular incidence

Inner most region has only the contribution from the sensor+ASIC (~0.4% X0)

Second innermost region contains the contribution from sensor, cooling plate and glue layer (~1.0% X0)



Materials considerations (500µm)





Materials considerations (Minimum wall, OD 1 mm / 200 bar)

Exercise to take into account the resistance to stress of the material

Rounded tubes maximum pressure (Barlow equation): $P = \frac{2\sigma w_t}{D}$ σ : yield strength w_t : wall thickness D: outer diameter

Very small in some cases (should be taken with a pint of salt)

Same exercise will be repeated using flexural strength



11/07/2024

Materials considerations (Minimum wall, OD 1 mm / 200 bar)

This is just an initial exercise for the selection of materials

Indicates that diamond/ceramics would be good candidates for the substrate

 Taking into account the capacity to deal with high pressure and material budget

Those number should still take into account thermal conductivity and thermal expansion mismatch

Preference for Diamond, SiC, (3D) Alumina, 3D titanium and BeO



Materials considerations (Minimum wall, OD 1 mm / 200 bar)



Preference for BeO, Diamond, Graphite, PyroidHT, SiC, Aluminum, Si and 3D AlSi10Mg based on thermal conductivity



To be as inclusive as possible, all possibilities below Kapton thermal expansion or below 10ppm/K (?)

Materials considerations



Metal 3D printing

- Collaboration with the Royce Institute (UK) based on Selective Laser Melting
- Revisit the plan-Z alternative and try to further reduce the material budget contribution
 - Main motivation: design flexibility and replaceability/price
- Three prototypes manufactured with different wall thicknesses (250 um, 150um and 100um)
 - To be tested for high pressure, leak tightness, ...
 - A quarter of a module approach (sensor, hybrid and GBTx region)



Metal 3D printing (FEA)

- Ti cooling tubes: with 250 um wall thickness
- Two cooling tubes under the silicon tile (similar to U1)
 - Silicon tile (400 um thick)
 - 12 W (2x higher than U1)
- Hottest region of the tile $\sim 25^{\circ}C$
 - About 3x higher than the plan-Z U1 measurements (around 8C)
- On the same model, TPG or graphene layer (1200 W/m.K) was considered to remove the heat of the GBTx
 - GBTx on top of Kapton/stycast layer (600um total, 1.25W/m.K)
 - Simulated as silicon 0.5x0.5cm and 5W
 - High $\Delta T \sim 90^{\circ}C$



3D metal printing + Pyroid HT (Very preliminary FEA)



VELO U1 (TDR stage)

VELO Upgrade I TDR



11/07/2024

Oscar (UoM)

Jan Buytaert (CERN)

VELO Module/Cooling concepts (CERN)

Sensor retraction during injection.

- In U0 and U1 the complete detector halves move.
- This scenario allows to move only the sensors of the inner rings, while the outer rings stay in place.
 - Rotating diaphragm mechanism similar as ALICE ? Any closing position is good, i.e. leaves no gaps !
 - Or 2 halves ?
 - More light-weigth, More precise ?



Open positions

VELO Module/Cooling concepts (Oxford)

Malcolm and Adam (Oxford)



Simplified FEA

5mm Overhang Added

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| * | | results | |

🐝 Thermal1 (-Temperature-)

| Mesh Details | Ø |
|--|------------------------------|
| Study name | Thermal 1* (·Default·) |
| DetailsMesh type | Solid Mesh |
| Mesher Used | Blended curvature-based mesh |
| Jacobian points for High quality mesh | At Nodes |
| Max Element Size | 0.2 mm |
| Min Element Size | 0.2 mm |
| Mesh quality | High |
| Total nodes | 834157 |
| Total elements | 418058 |
| Maximum Aspect Ratio | 12.045 |
| Percentage of elements with Aspect Ratio < 3 | 75.9 |
| Percentage of elements with Aspect Ratio > 10 | 0.00789 |
| Percentage of distorted elements | 0 |
| Number of distorted elements | 0 |
| Remesh failed parts independently | Off |
| Time to complete mesh(hh:mm:ss) | 00:00:22 |
| Computer name | |

37.8 33.6 20.9 16.7 8.25



Temp (Kelvin 42

> 29.3 25.1

12.5

4.04

-0.181

VELO Module/Cooling concepts (NIKHEF)

Kazu/Yutaro presentation



• Features:

- Mountable modules using cooling connectors
- Carbon fiber (or aluminum, etc) frame with high stiffness for all degrees of freedom (DoF) with minimal material
- Allows different station design depending on location.
- Integrated supply of power and coolant (next slide).



VELO Module/Cooling concepts (NIKHEF)

Kazu/Yutaro presentation



Jan Buytaert (CERN)

VELO Module/Cooling concepts (CERN) Current VELO (U1)



Jan Buytaert (CERN)

VELO Module/Cooling concepts (CERN)

Circular layout

- Aim for more uniform phi coverage in center and periphery.
- Also 24 sensors. Each sensor is 14mmx14mm
- Composed of 2 large and 2 small "rings". Different colors on different z-planes

Zoom on center hole





VELO Module/Cooling concepts (Oxford)

Malcolm and Adam (Oxford)





VELO Module/Cooling concepts (NIKHEF)

Kazu/Yutaro presentation

Some additional ideas

- Additional sensor ring
 - Increases outer radius
 - Reduces number of stations (Avg. Number of hits)
 - Allows sensors in the outer ring at an angle



Module

ring